

# INA6006AP1

FOR LOW FREQUENCY AMPLIFY APPLICATION  
SILICON PNP EPITAXIAL TYPE

## DESCRIPTION

INA6006AP1 is a silicon PNP transistor.

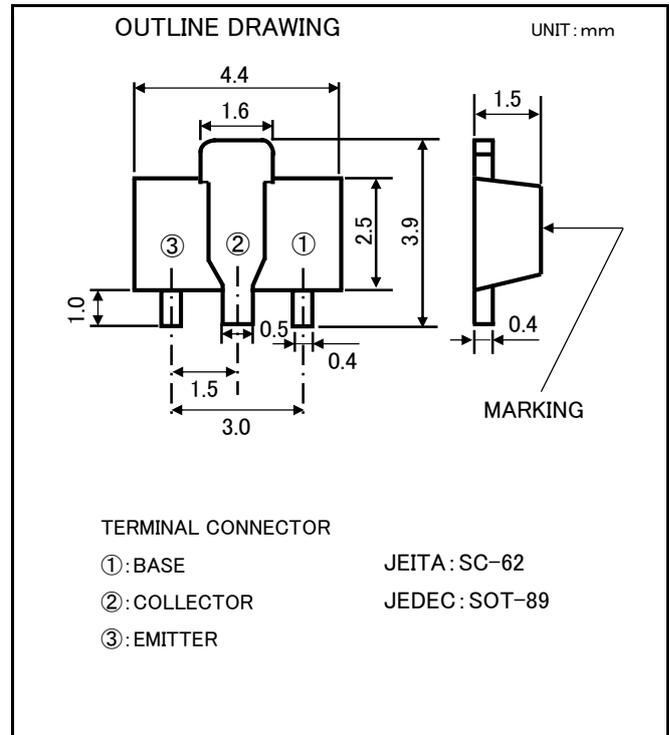
It is designed with high voltage.

## FEATURE

- Small package for easy mounting.
- High voltage  $V_{CEO} = -150V$
- Low voltage  $V_{CE(sat)} = -0.5V(\text{MAX})$
- Complementary : INC6006AP1

## APPLICATION

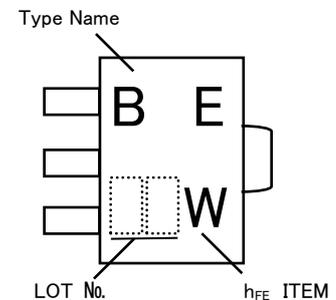
High voltage switching.



## MAXIMUM RATING (Ta=25°C)

| SYMBOL    | PARAMETER                      | RATING   | UNIT |
|-----------|--------------------------------|----------|------|
| $V_{CBO}$ | Collector to Base voltage      | -160     | V    |
| $V_{EBO}$ | Emitter to Base voltage        | -5       | V    |
| $V_{CEO}$ | Collector to Emitter voltage   | -150     | V    |
| $I_C$     | Collector current              | -100     | mA   |
| $I_{CM}$  | Peak collector current         | -200     | mA   |
| $P_C$     | Collector dissipation(Ta=25°C) | 500      | mW   |
| $T_j$     | Junction temperature           | +150     | °C   |
| $T_{stg}$ | Storage temperature            | -55~+150 | °C   |

## MARKING



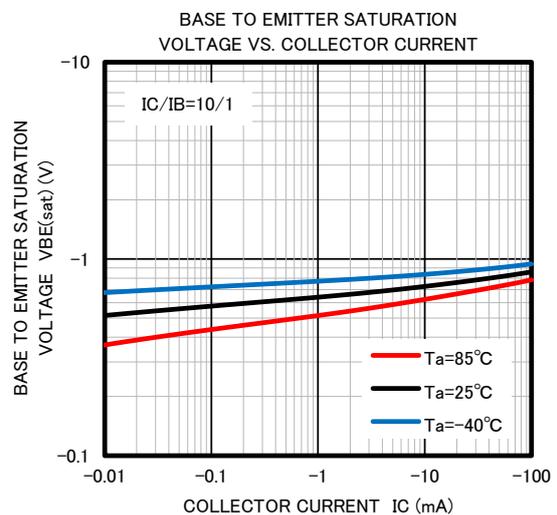
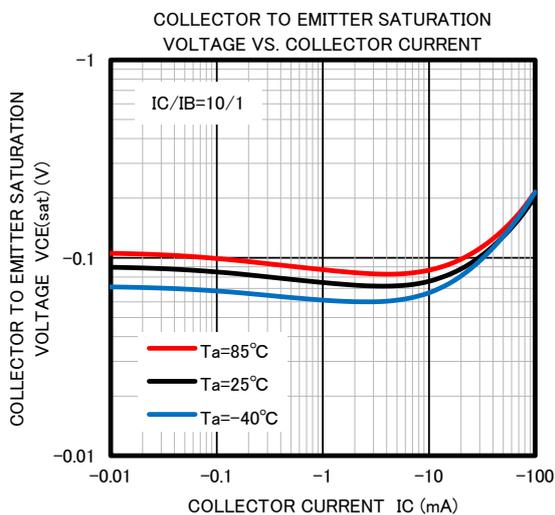
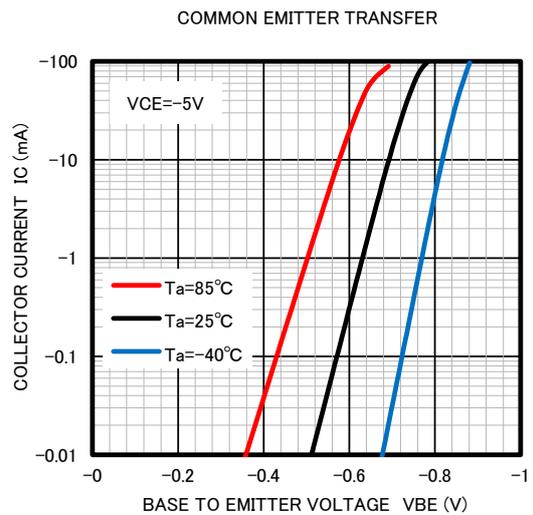
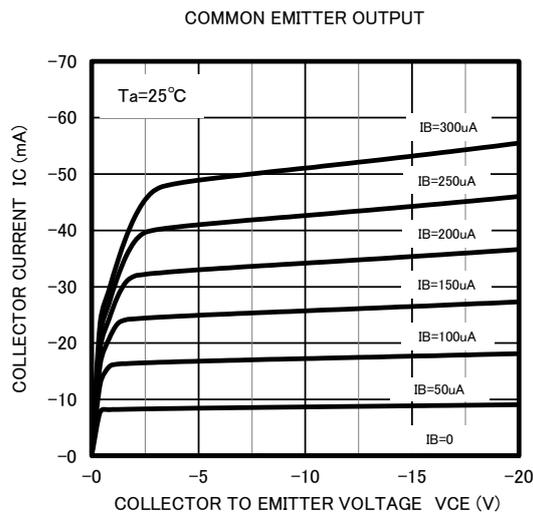
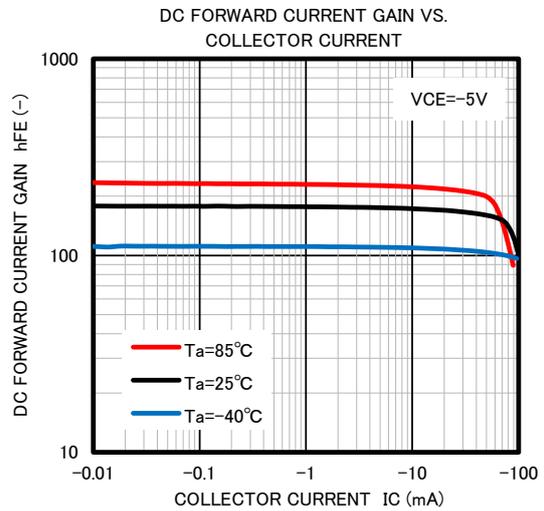
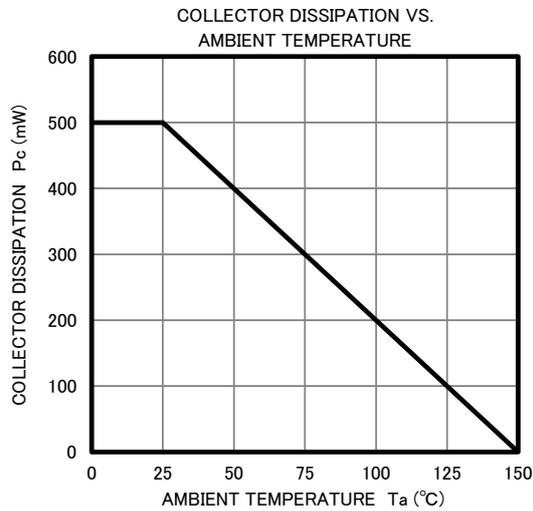
## ELECTRICAL CHARACTERISTICS (Ta=25°C)

| SYMBOL         | PARAMETER                    | TEST CONDITIONS                      | LIMITS |     |       | UNIT |
|----------------|------------------------------|--------------------------------------|--------|-----|-------|------|
|                |                              |                                      | MIN    | TYP | MAX   |      |
| $V_{(BR)CBO}$  | C to B breakdown voltage     | $I_C = -100 \mu A, I_E = 0mA$        | -160   | -   | -     | V    |
| $V_{(BR)EBO}$  | E to B breakdown voltage     | $I_E = -10 \mu A, I_C = 0mA$         | -5     | -   | -     | V    |
| $V_{(BR)CEO}$  | C to E breakdown voltage     | $I_C = -1mA, R_{BE} = \infty$        | -150   | -   | -     | V    |
| $I_{CBO}$      | Collector cut off current    | $V_{CB} = -120V, I_E = 0mA$          | -      | -   | -100  | nA   |
| $I_{EBO}$      | Emitter cut off current      | $V_{EB} = -3V, I_C = 0mA$            | -      | -   | -100  | nA   |
| $h_{FE1}$      | DC forward current gain1     | $V_{CE} = -5V, I_C = -1mA$           | 45     | -   | -     | -    |
| $h_{FE2}$      | DC forward current gain2     | $V_{CE} = -5V, I_C = -10mA$          | 90     | -   | 270   | -    |
| $h_{FE3}$      | DC forward current gain3     | $V_{CE} = -5V, I_C = -50mA$          | 45     | -   | -     | -    |
| $V_{CE(sat)1}$ | C to E saturation voltage1   | $I_C = -10mA, I_B = -1mA$            | -      | -   | -0.2  | V    |
| $V_{CE(sat)2}$ | C to E saturation voltage2   | $I_C = -50mA, I_B = -5mA$            | -      | -   | -0.5  | V    |
| $V_{BE(sat)1}$ | B to E saturation voltage1   | $I_C = -10mA, I_B = -1mA$            | -      | -   | -1.0  | V    |
| $V_{BE(sat)2}$ | B to E saturation voltage2   | $I_C = -50mA, I_B = -5mA$            | -      | -   | -1.0  | V    |
| $V_{BE(on)}$   | B to E on voltage            | $V_{CE} = -5V, I_C = -10mA$          | -      | -   | -0.77 | V    |
| fT             | Gain bandwidth product       | $V_{CE} = -10V, I_E = 10mA$          | 100    | -   | 300   | MHz  |
| Cob            | Collector output capacitance | $V_{CB} = -10V, I_E = 0mA, f = 1MHz$ | -      | 2.8 | 6     | pF   |

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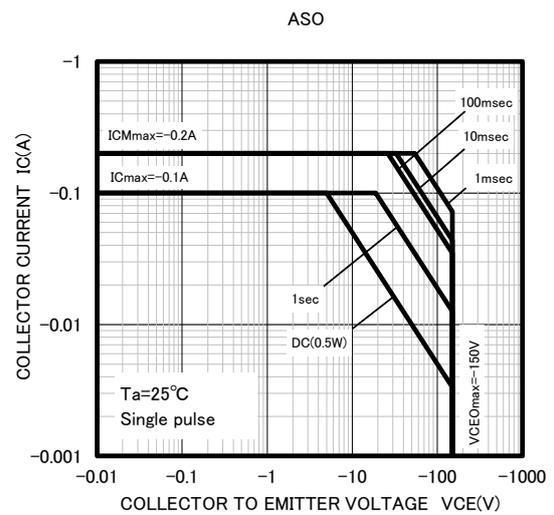
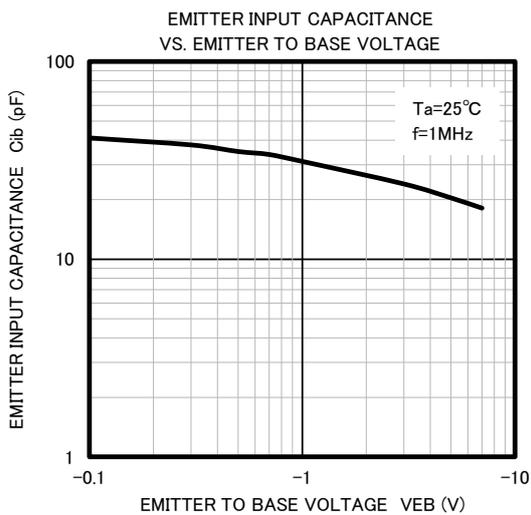
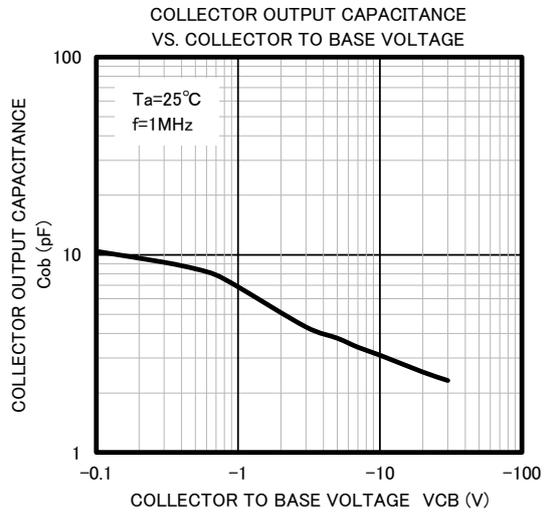
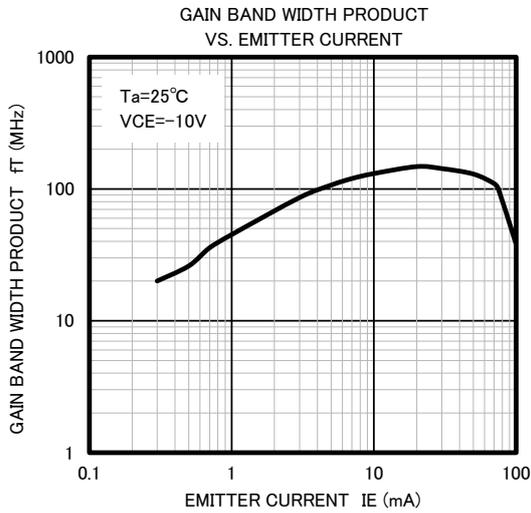
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## TYPICAL CHARACTERISTICS



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